



# DDR3 SDRAM SO-DIMM MODULE, 1.5V 2GByte - 256MX64 AVH6456U61F9333G1-AP

## FEATURES

JEDEC DDR3 PC3-10600 1333MT/s, Lead-Free, RoHS compliant

- Clock frequency: 667MHz with CAS latency 9
- 256 byte serial EEPROM
- Data input and output masking
- Programmable Partial Array Self-Refresh (PASR)
- Programmable Output driver impedance control
- Programmable CAS latency: 9
- Fixed Burst lengths (BL) of 8 and Burst Chop (BC) of 4
- Selectable BL8 or BC4 on the fly (OTF)
- Gold card edge fingers
- 8K refresh per 64ms
- Low active and standby current consumption
- On Die Termination (ODT)
- Auto refresh and self refresh capability
- Double-sided module
- 30mm (1.181 inch) height

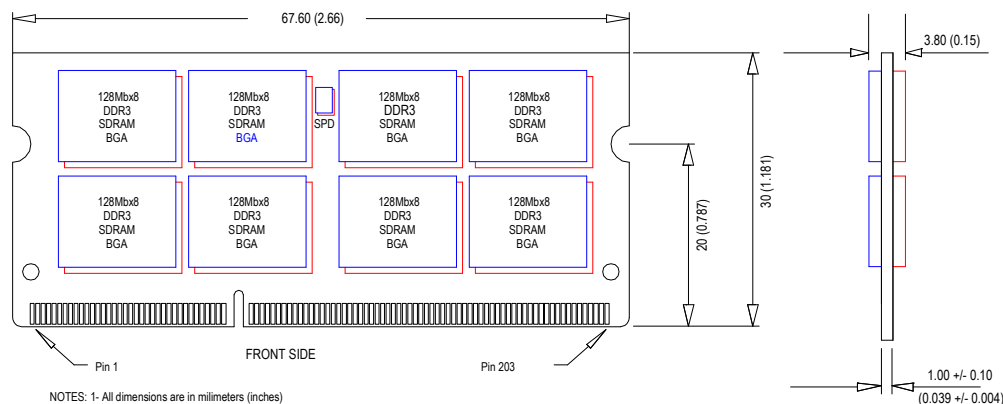
## DESCRIPTION

The AVH6456U61F9333G1-AP is an Unbuffered DDR3 SDRAM SODIMM memory module. This module is MO-268 R/C F small-outline, dual in-line memory module. A 256 byte serial EEPROM on board can be used to store module information such as timing, configuration, density, etc.

The AVH6456U61F9333G1-AP memory module is 2GByte and organized as a 256MX64 array using (16) 128MX8 DDR3 SDRAMs in lead-free FBGA packages.

All memory modules are fabricated using the latest technology design, eight-layer printed circuit board substrate construction with low ESR decoupling capacitors on-board for high reliability and low noise.

## PHYSICAL DIMENSIONS



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INVENTORY	MOD. TYPE	ORG.	DENSITY	PARITY	TYPE	VOLT.	FEATURE	SPEED	MODE	REV
AV = AVANT	H = 204-PIN SO-DIMM	64 = X64	56 = 256M	U=UNBUFFERED	61 = 16Mx8x8 (128Mx8)	F = 1.5V	9 = CAS LATENCY 9	1333MT/s	G = DDR3 SDRAM	REV=1

Other options may be available. Call for specific part number information on options not listed.



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